

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In application of: RAMINDA U. MADURAWÉ
Application No.:
Title: Insulated-Gate Field-Effect Thin Film Transistors
Filed: 01/20/2004

INFORMATION DISCLOSURE STATEMENT SUBMISSION

Sirs:

Attached is IDS form 1449 for the Application submitted herewith entitled "Insulated-Gate Field-Effect Thin Film Transistors", said application a division of Application Serial No 10/413,808 filed on Apr. 14, 2003, copies of said IDS references filed on Jul 31, 2003.

Regards,



Raminda U. Madurawe


CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

on January 20, 2004

By:



Raminda U. Madurawe

Please type a plus sign (+) inside this box



PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031
U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet 1 of 2

Complete if Known

Application Number	
Filing Date	01/20/2004
First Named Inventor	Madurawe, Raminda U.
Group Art Unit	
Examiner Name	
Attorney Docket Number	

U.S. PATENT DOCUMENTS

Examiner Initials *	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
		4,065,781		Gutknecht	12-27-1977	
		4,502,204		Togashi et al.	03-05-1985	
		5,266,515		Robb et al.	11-30-1993	
		5,340,999		Takeda et al.	08-23-1994	
		5,537,078		Strong	07-16-1996	
		5,656,844		Klein et al.	08-12-1997	
		5,981,317		French et al.	11-09-1999	
		6,107,642		Sundaresan	08-22-2000	
		6,222,234		Imai	04-24-2001	
		6,271,063		Chan et al.	08-07-2001	
		2001/0041399		Bonart	11-15-2001	
		6,380,009		Battersby	04-30-2002	
		6,406,951		Yu	06-18-2002	
		2002/0168804		Van der Zaag et al.	11-14-2002	
		6,545,319		Deane et al.	04-08-2003	
		2002/0079496		Deane et al.	06-27-2002	
		6,579,750		Krivokapic	06-17-2003	
		6,339,244		Krivokapic	01-15-2002	

FOREIGN PATENT DOCUMENTS

Examiner Initials *	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
								<input type="checkbox"/>
								<input type="checkbox"/>
								<input type="checkbox"/>
								<input type="checkbox"/>
								<input type="checkbox"/>
								<input type="checkbox"/>
								<input type="checkbox"/>
								<input type="checkbox"/>

Examiner
Signature

Date
Considered

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.